

# Electron-phonon calculations for metals, insulators, and superconductors

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Department of Materials, University of Oxford



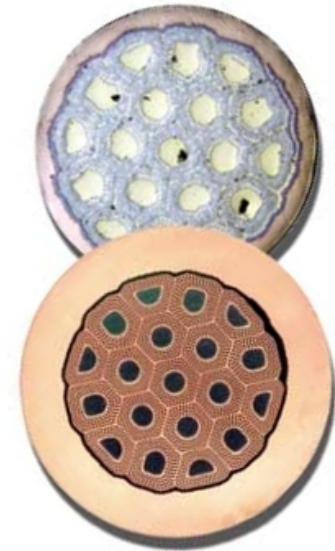
## Metals

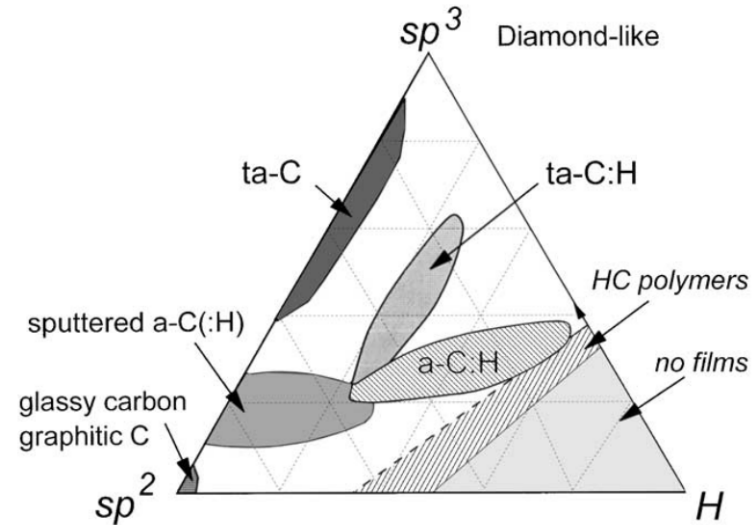
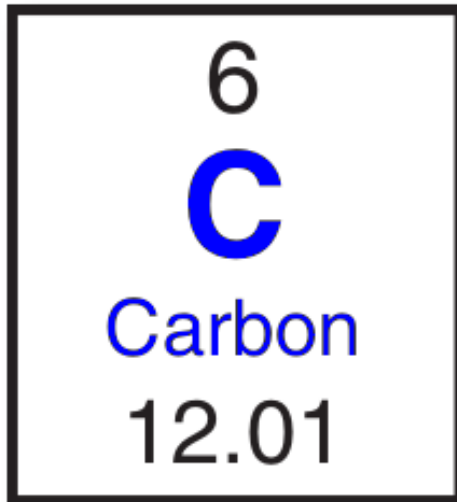


## Insulators



## Superconductors





J Robertson, Mat Sci Eng 2002

TABLE II. Radii (in atomic units) for maxima in radial wave functions of atomic C, Si, and Ge. The values  $r_s$  and  $r_p$  are for valence  $s, p$  orbitals of the  $s^1p^3$  atomic configuration. The value  $r_d$  is for the  $d$  orbital of the  $s^1p^2d^1$  atomic configuration.

	$r_s$	$r_p$	$r_d$
C	1.21	1.21	8.51
Si	1.75	2.13	4.89
Ge	1.76	2.14	6.25

MT Yin & ML Cohen, PRL 1983

## Metals



## Insulators

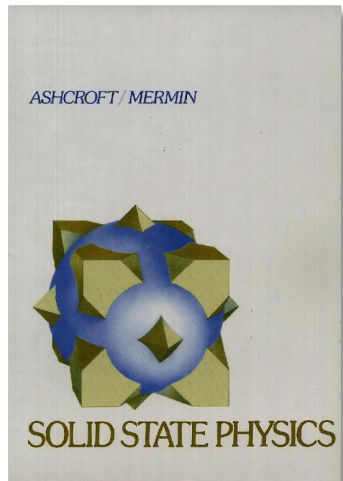


## Superconductors

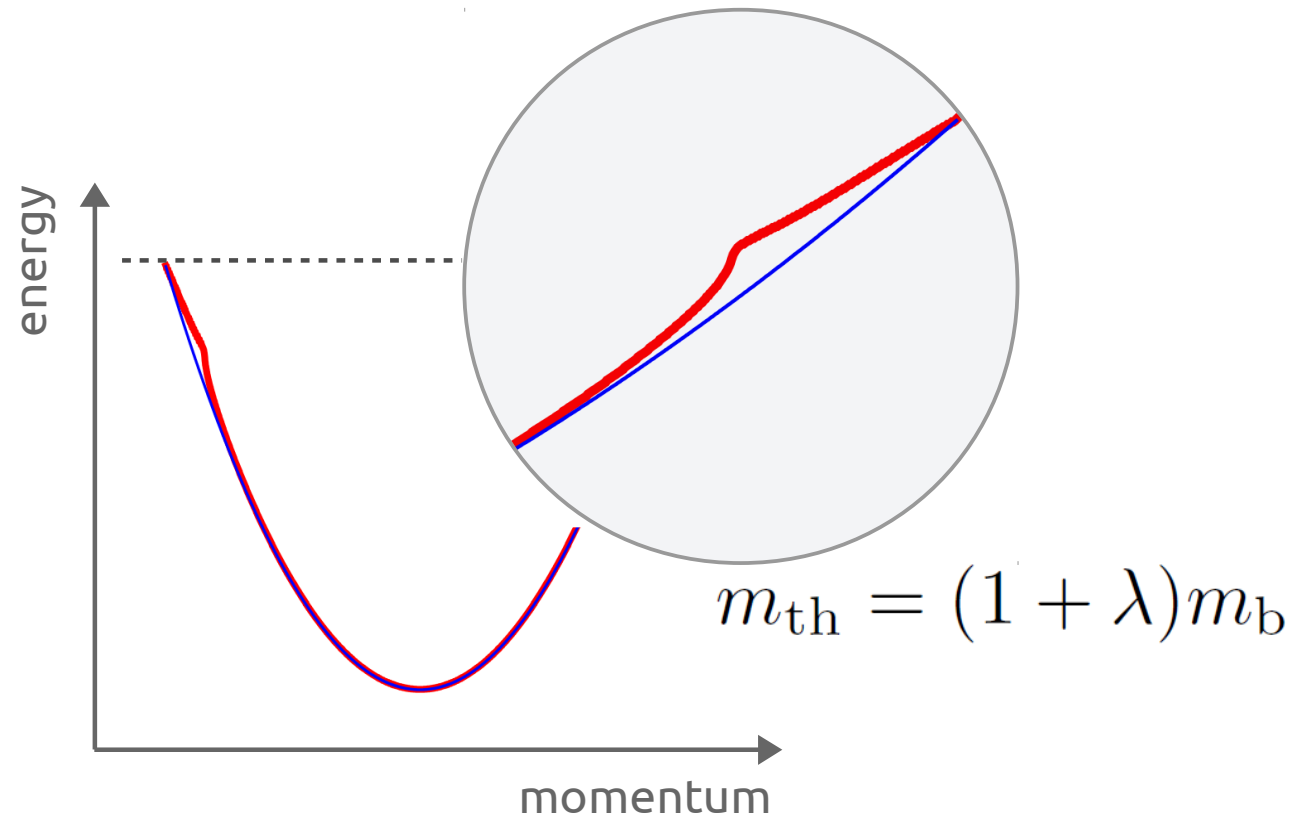


## Mass enhancement in **metals**

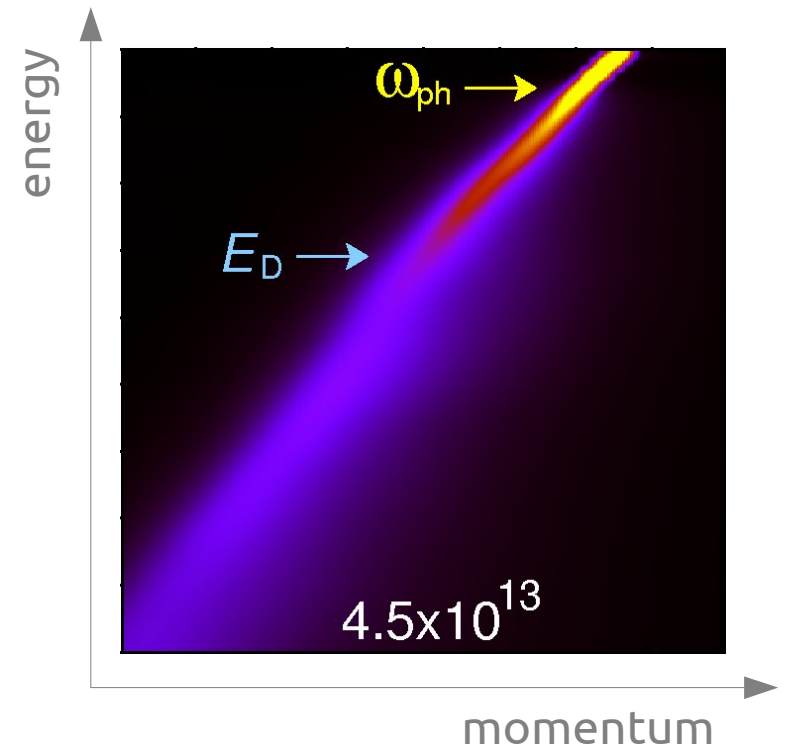
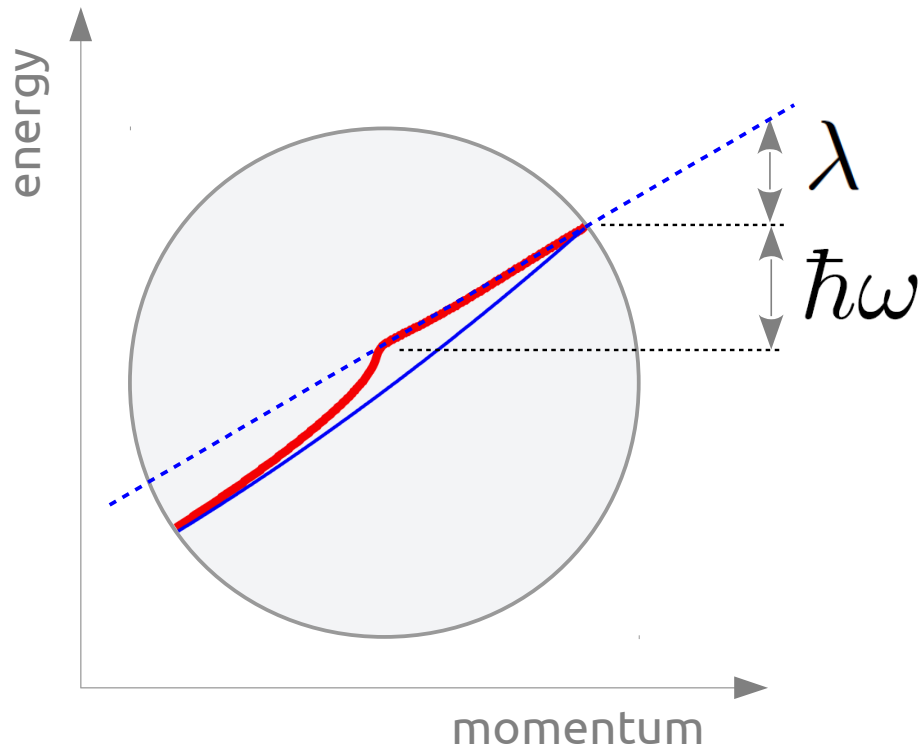
low-T heat capacity



p. 521



## ARPES kinks in 2D materials



CH Park, FG et al, Nano Lett 2009

# Quasiparticle theory of e-ph interaction in metals

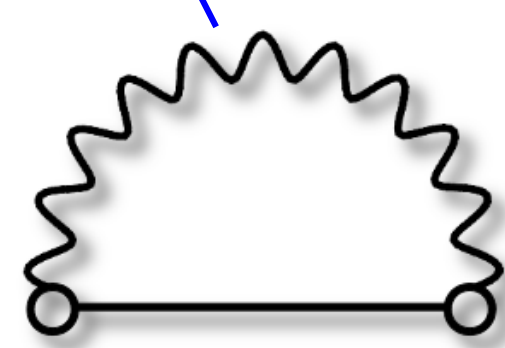
S Engelsberg, JR Schrieffer, Phys Rev 1963

$$G(\mathbf{k}, \omega) = \frac{1}{\omega - \epsilon_{\mathbf{k}} - \Sigma(\mathbf{k}, \omega)}$$

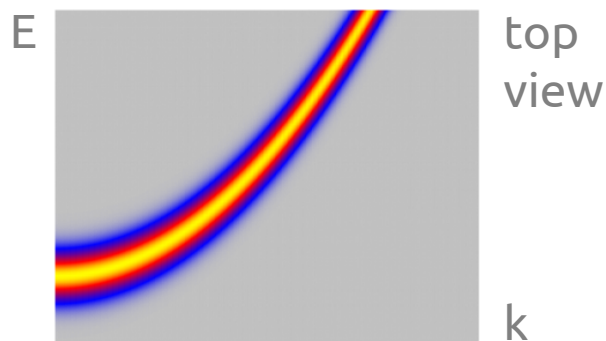
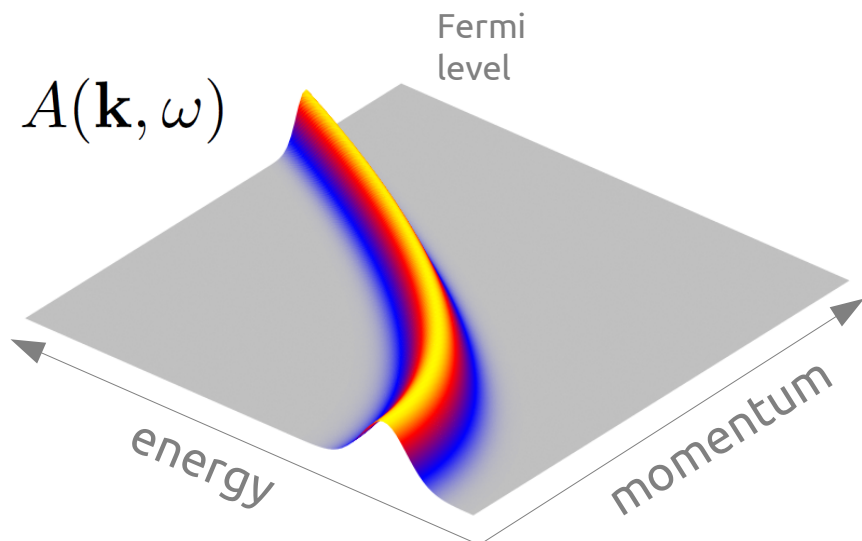
$$A(\mathbf{k}, \omega) = \frac{1}{\pi} |\text{Im}G(\mathbf{k}, \omega)|$$

Holstein model + Migdal theorem

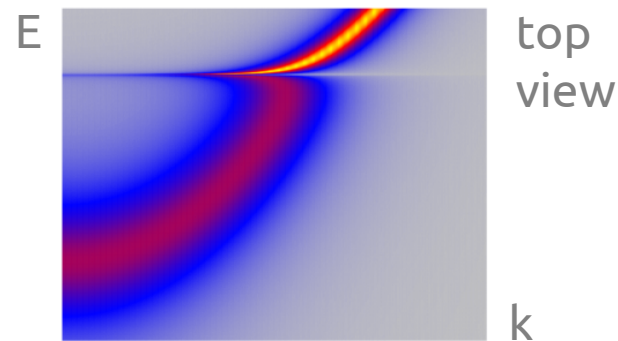
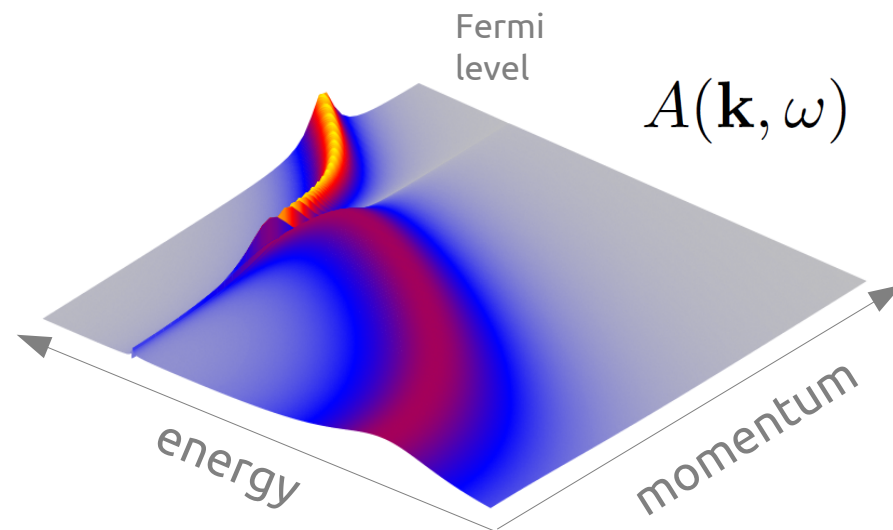
$$\hat{H}_{\text{ep}} = g \sum_{\mathbf{k}, \mathbf{q}} a_{\mathbf{k}+\mathbf{q}}^\dagger a_{\mathbf{k}} (b_{\mathbf{q}} + b_{-\mathbf{q}}^\dagger)$$



Non-interacting



Including e-ph interaction



See also: A Eiguren, C Ambrosch-Draxl, PM Echenique, PRB 2009



# First-principles theory of e-ph interaction

L Hedin and S Lundqvist, Solid State Physics 1969

GW framework

$$\Sigma_{\text{ph}}(\mathbf{x}, \mathbf{x}'; \omega) = \frac{i}{2\pi} \int_{-\infty}^{+\infty} d\omega' G(\mathbf{x}, \mathbf{x}', \omega + \omega') W_{\text{ph}}(\mathbf{r}, \mathbf{r}', \omega') e^{i\omega'\delta}$$

**Ionic contribution** to screened Coulomb interaction

$$W_{\text{ph}}(\mathbf{r}, \mathbf{r}'; \omega) = \sum_{\nu} \int \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{2\omega_{\mathbf{q}\nu}}{\omega^2 - \omega_{\mathbf{q}\nu}^2} \Delta V_{\mathbf{q}\nu}(\mathbf{r}) \Delta V_{\mathbf{q}\nu}^*(\mathbf{r}')$$

$$\Sigma_{n\mathbf{k}}(\omega) = \sum_{m\nu} \int \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} |g_{mn,\nu}(\mathbf{k}, \mathbf{q})|^2 \times \text{matrix elements}$$

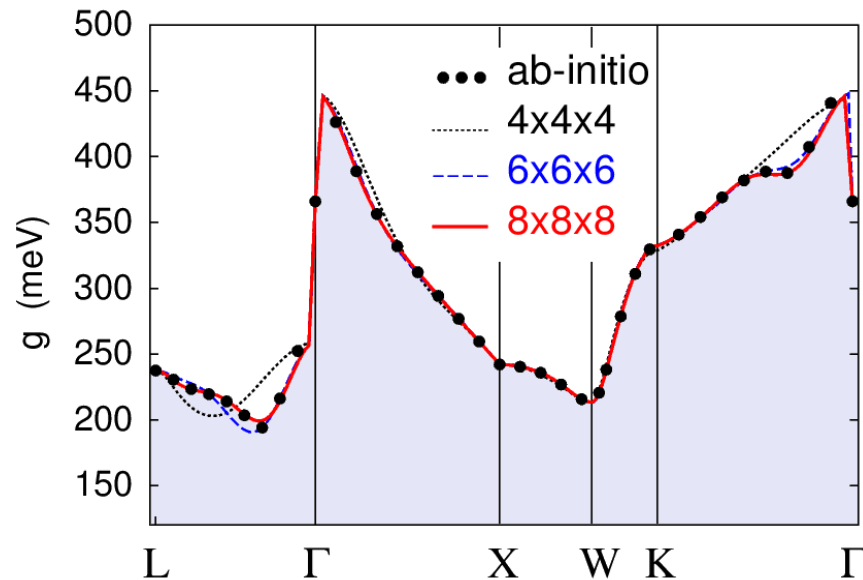
$$\times \left[ \frac{1 - f_{m\mathbf{k}+\mathbf{q}} + n_{\mathbf{q}\nu}}{\omega - \epsilon_{m\mathbf{k}+\mathbf{q}} - \omega_{\mathbf{q}\nu} - i\delta} + \frac{f_{m\mathbf{k}+\mathbf{q}} + n_{\mathbf{q}\nu}}{\omega - \epsilon_{m\mathbf{k}+\mathbf{q}} + \omega_{\mathbf{q}\nu} - i\delta} \right]$$

electrons
phonons

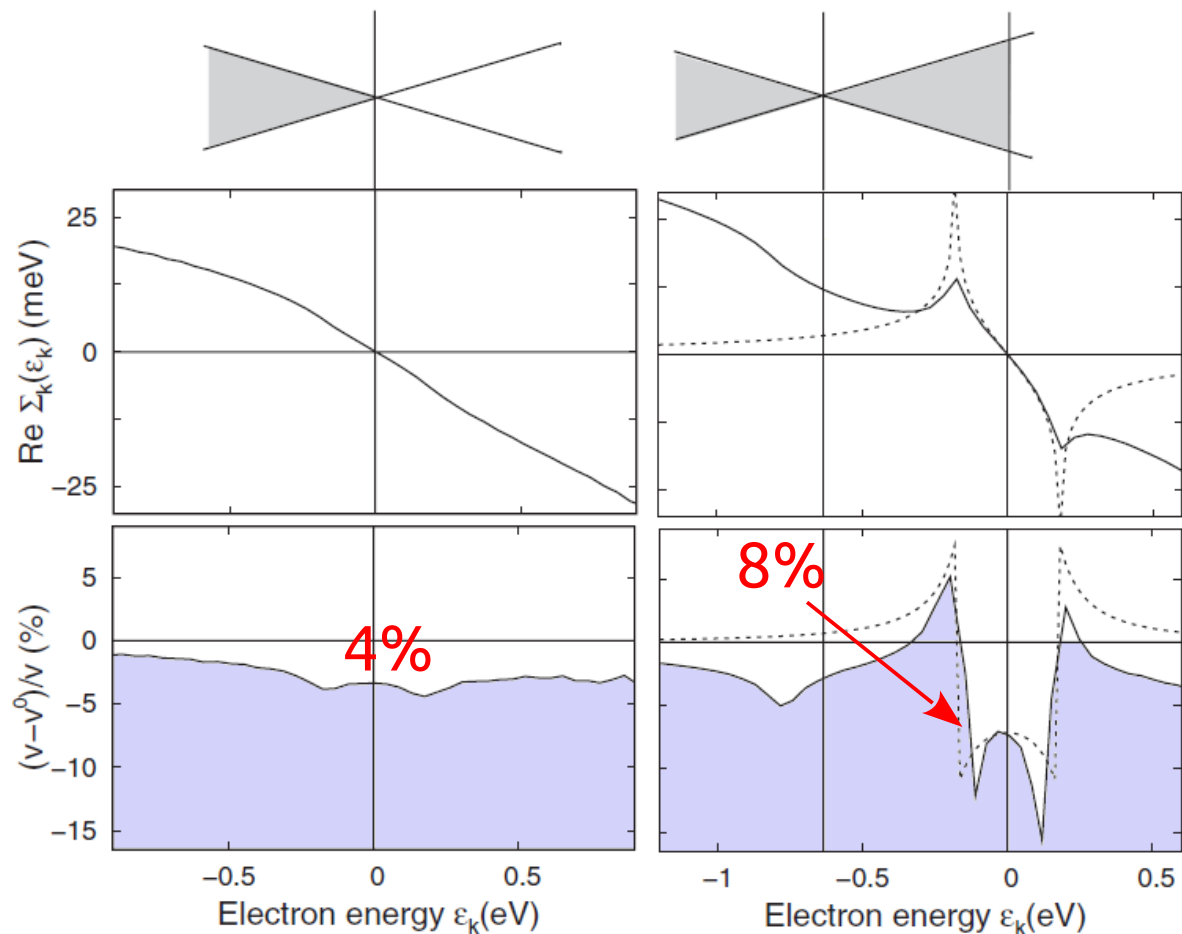
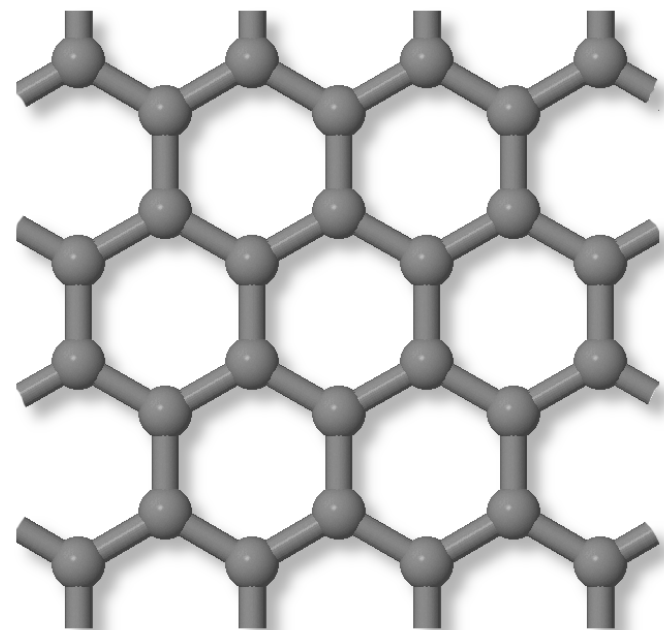
Wannier e-ph interpolation



FG, ML Cohen, SG Louie, PRB 2007



## Example: graphene



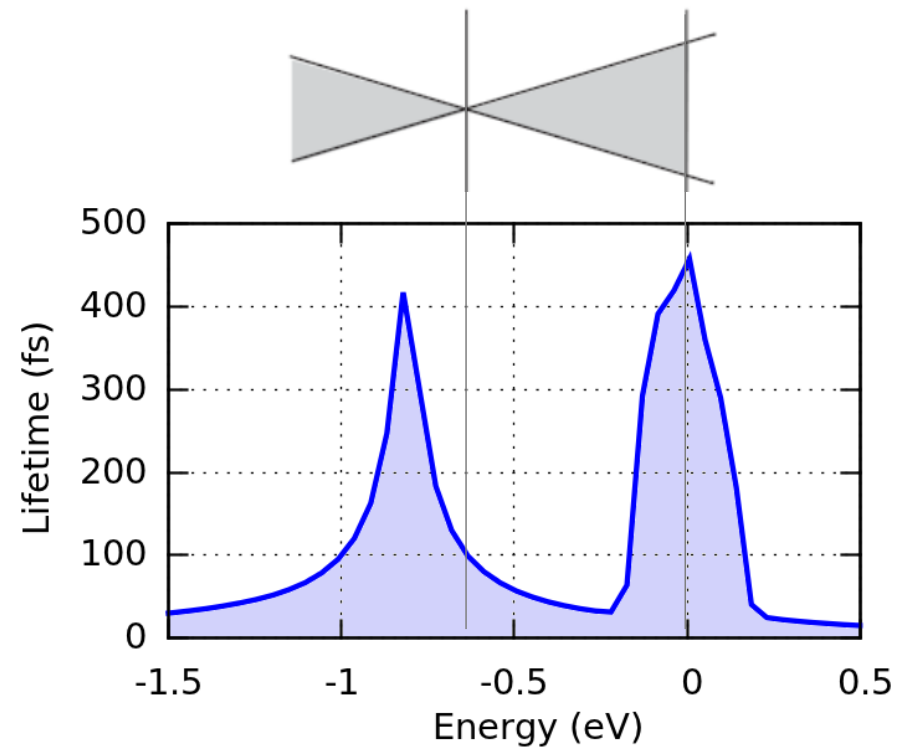
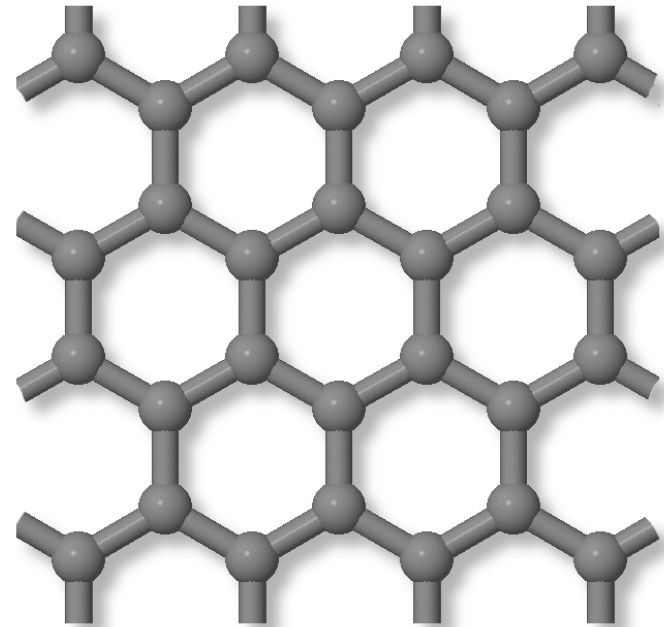
pristine

$4 \cdot 10^{13}$  electrons/cm<sup>2</sup>

CH Park, FG, ML Cohen, SG Louie, PRL 2007

## Example: graphene

$$\tau_{n\mathbf{k}} = \frac{\hbar}{2\text{Im}\Sigma_{n\mathbf{k}}}$$



$4 \cdot 10^{13}$  electrons/cm<sup>2</sup>

CH Park, FG, ML Cohen, SG Louie, PRL 2007

## Metals



## Insulators

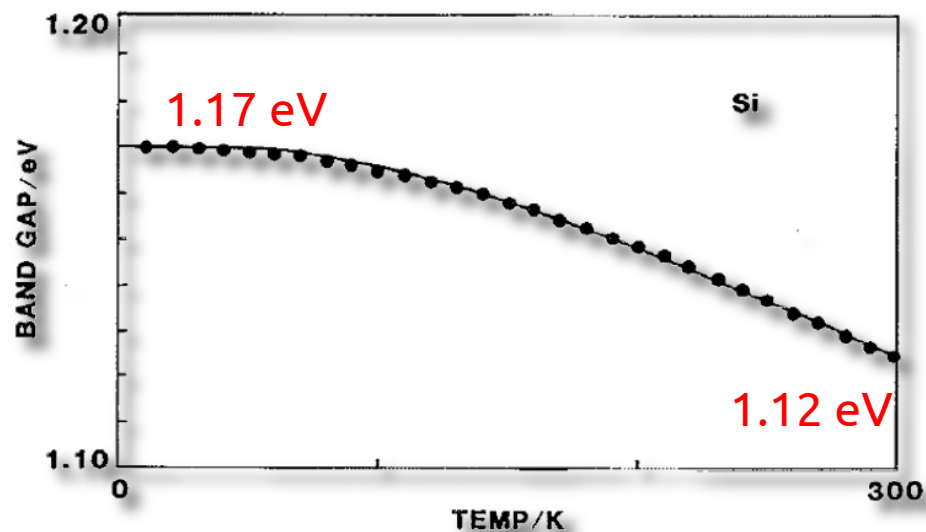


## Superconductors

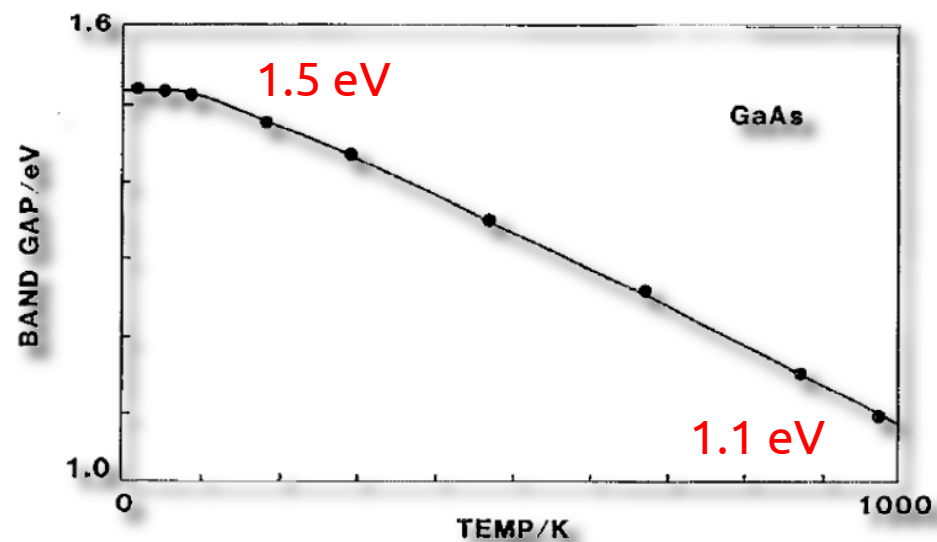


## Temperature dependence of band gaps

silicon



gallium arsenide



KP O'Donnel, X Chen, Appl Phys Lett 1991

REVIEWS OF MODERN PHYSICS, VOLUME 77, OCTOBER 2005

## Isotope effects on the optical spectra of semiconductors

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(Published 7 November 2005)

Since the end of the cold war, macroscopic amounts of separated stable isotopes of most elements have been available "off the shelf" at affordable prices. Using these materials, single crystals of many semiconductors have been grown and the dependence of their physical properties on isotopic composition has been investigated. The most conspicuous effects observed have to do with the dependence of phonon frequencies and linewidths on isotopic composition. These affect the electronic properties of solids through the mechanism of electron-phonon interaction, in particular, in the corresponding optical excitation spectra and energy gaps. This review contains a brief introduction to the history, availability, and characterization of stable isotopes, including their many applications in science and technology. It is followed by a concise discussion of the effects of isotopic composition on the vibrational spectra, including the influence of average isotopic masses and isotopic disorder on the phonons. The final sections deal with the effects of electron-phonon interaction on energy gaps, the concomitant effects on the luminescence spectra of free and bound excitons, with particular emphasis on silicon, and the effects of isotopic composition of the host material on the optical transitions between the bound states of hydrogenic impurities.

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Y Fan, Phys Rev **1951**

E. Antoncik, Czechosl J Phys **1955**

PB Allen, V Heine, J Phys C **1976**

M Cardona et al, **1970–**

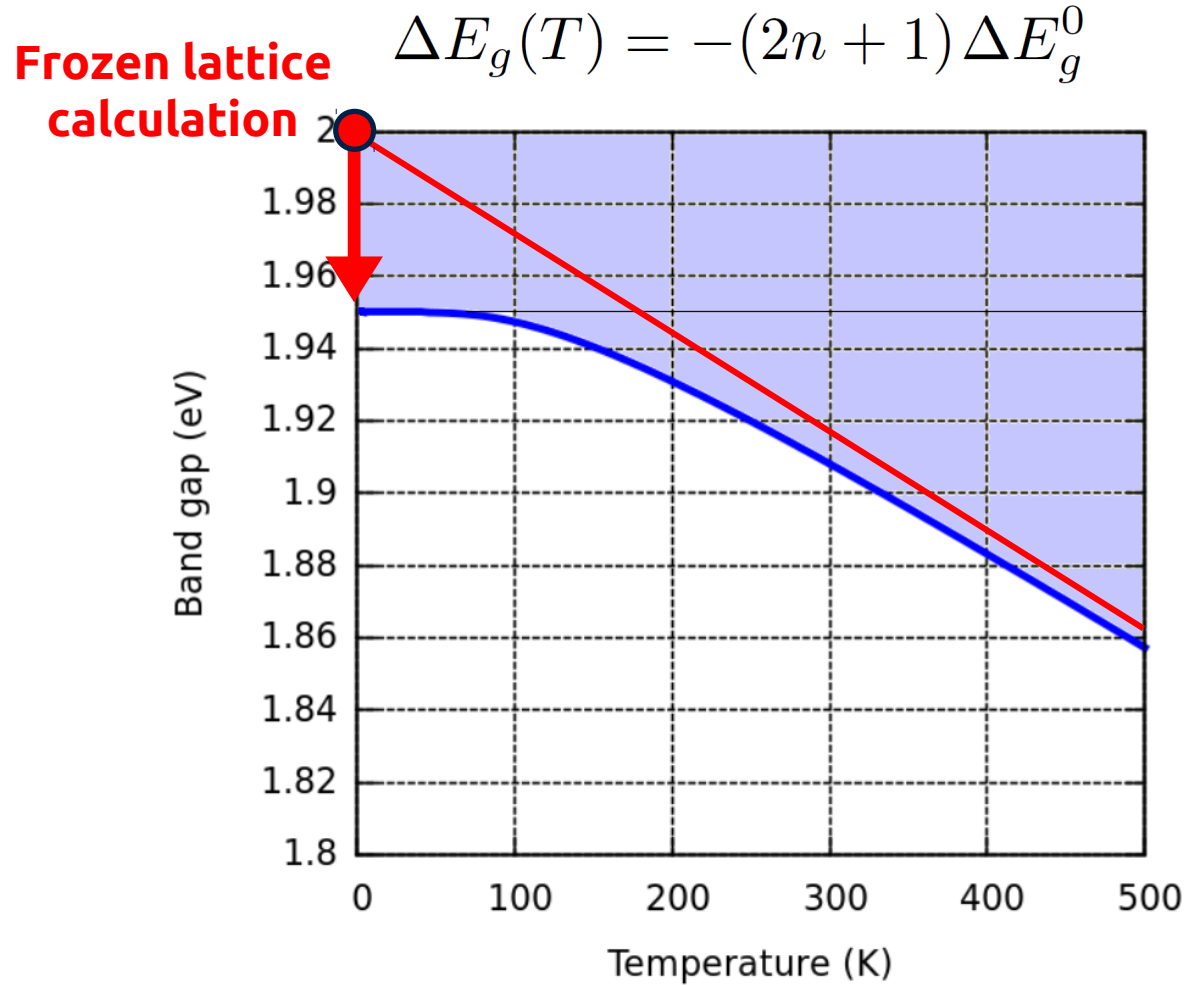
CP Herrero, R Ramírez, ER Hernández, PRB **2006**

A Marini, PRL **2008**

FG, SG Louie, ML Cohen, PRL **2010**

X Gonze, P Boulanger, M Coté, Ann Phys **2010**

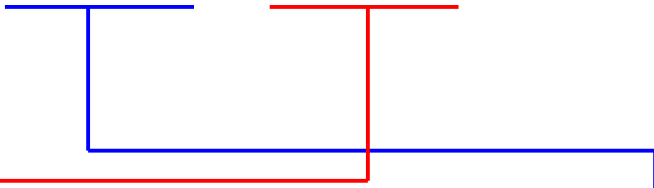
E Cannuccia, A Marini, PRL **2011**



M Cardona & MLW Thewalt, Rev Mod Phys 2005



$$V(u) = V^0 + \frac{\partial V}{\partial u} u + \frac{1}{2} \frac{\partial^2 V}{\partial u^2} u^2$$

$$E_{n\mathbf{k}}(u) = E_{n\mathbf{k}}^0 + \langle n\mathbf{k} | \text{red dot} | n\mathbf{k} \rangle + \sum_{m\mathbf{q}} \frac{|\langle m\mathbf{k} + \mathbf{q} | \text{blue dot} | n\mathbf{k} \rangle|^2}{E_{n\mathbf{k}}^0 - E_{m\mathbf{k}+\mathbf{q}}^0}$$


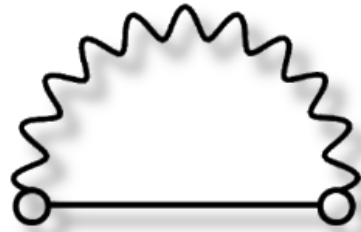


- Thermal average of displacements
- Harmonic
- Adiabatic
- Semiclassical

Allen & Heine, J Phys C 1976

$$\Delta \epsilon_{n\mathbf{k}} = \Delta^{\text{SE}} \epsilon_{n\mathbf{k}} + \Delta^{\text{DW}} \epsilon_{n\mathbf{k}}$$

Fan (self-energy)

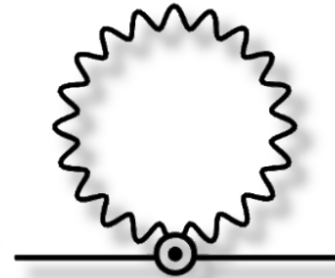


$$\Delta^{\text{SE}} \epsilon_{n\mathbf{k}} = \sum_{m \neq n, \nu} \int \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{2n_{\mathbf{q}\nu} + 1}{\epsilon_{n\mathbf{k}} - \epsilon_{m\mathbf{k}+\mathbf{q}}} |g_{mn,\nu}(\mathbf{k}, \mathbf{q})|^2$$

the same term as for metals

$$\Delta\epsilon_{n\mathbf{k}} = \Delta^{\text{SE}}\epsilon_{n\mathbf{k}} + \Delta^{\text{DW}}\epsilon_{n\mathbf{k}}$$

Debye-Waller



$$\Delta^{\text{DW}}\epsilon_{n\mathbf{k}} = - \sum_{m \neq n, \nu} \int \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{2n_{\mathbf{q}\nu} + 1}{\epsilon_{n\mathbf{k}} - \epsilon_{m\mathbf{k}}} [g_{mn, \nu}^{\text{DW}}(\mathbf{k}, \mathbf{q})]^2$$

essential for the theory to be translationally invariant

$$\Delta^{\text{DW}} \epsilon_{n\mathbf{k}} = - \sum_{m \neq n, \nu} \int \frac{d\mathbf{q}}{\Omega_{\text{BZ}}} \frac{2n_{\mathbf{q}\nu} + 1}{\epsilon_{n\mathbf{k}} - \epsilon_{m\mathbf{k}}} [g_{mn, \nu}^{\text{DW}}(\mathbf{k}, \mathbf{q})]^2$$

$$[g_{mn, \nu}^{\text{DW}}(\mathbf{k}, \mathbf{q})]^2 = \frac{1}{2\omega_{\mathbf{q}\nu}} \sum_{\mu\mu'} t_{\mu\mu'}^{\nu}(\mathbf{q}) h_{mn, \mu}^*(\mathbf{k}) h_{mn, \mu'}(\mathbf{k}),$$

$$t_{\kappa\alpha, \kappa'\alpha'}^{\nu}(\mathbf{q}) = u_{\nu, \kappa\alpha}^*(\mathbf{q}) u_{\nu, \kappa'\alpha'}(\mathbf{q}) + u_{\nu, \kappa'\alpha}^*(\mathbf{q}) u_{\nu, \kappa\alpha'}(\mathbf{q})$$

$$h_{mn, \mu}(\mathbf{k}) = \sum_{\nu} u_{\mu\nu}^{-1}(\mathbf{0}) \omega_{\mathbf{0}\nu}^{1/2} g_{mn, \nu}(\mathbf{k}, \mathbf{0}).$$

PHYSICAL REVIEW B

VOLUME 26, NUMBER 3

1 AUGUST 1982

Generalization of the theory of the electron-phonon interaction:  
Thermodynamic formulation of superconducting- and normal-state properties

Warren E. Pickett

Naval Research Laboratory, Washington, D.C. 20375

(Received 25 January 1982)

A thermodynamic formulation for the electron self-energy is given which is applicable when the electronic spectrum possesses structure on the scale of phonon frequencies, provided only that the ratio of phonon phase velocity to electron Fermi velocity is small. Electron-phonon, Coulomb, and electron-defect interactions are included on an equal footing and it is shown that their different frequency dependencies lead to specific effects on the Eliashberg self-energy: (a) The Coulomb interaction contributes nothing of essence to the normal-state self-energy (in this isotropic approximation) but retains its usual depairing effect upon the superconducting gap function, (b) defects affect superconducting properties primarily through a broadening of the electronic spectrum, and (c) phonons contribute a thermal shift and broadening as well as the mass enhancement. A generalization to *intensive* electron-phonon, electron-electron, and electron-defect interaction constants is necessary to redevelop an intuition into the effects of these interactions. The change in the structure of the Eliashberg equation due to a nonconstant density of states (DOS) and the consequent interplay between static and thermal disorder is analyzed in detail, with a central feature being the change in frequency dependence of the self-energy compared to a constant DOS solution. The effect of DOS structure on the superconducting transition temperature  $T_c$ , which is manifested in the defect dependence of  $T_c$ , is analyzed in detail. Further it is proposed that an extension of the self-consistent Eliashberg approach be extended above  $T_c$  to determine the normal-state self-energy and thereby the electronic contribution to thermodynamic quantities. Phonon broadening is shown to affect the spin susceptibility at finite temperature. Reinterpretation of several of the anomalous properties of *A15* compounds in terms of the present theory is suggested. Several aspects of the theory are compared to experimental data for Nb<sub>3</sub>Sn.

I. INTRODUCTION

Deeply ingrained in the formal theory of the interacting electron-phonon (*e-ph*) system in metals are two simplifying approximations. The first is an extension of the adiabatic, or Born-Oppenheimer approximation<sup>1</sup> in which the light electrons are considered to respond instantaneously to the heavy ions (of mass  $M$ ). Central to the theory of *e-ph* systems is Migdal's theorem,<sup>2</sup> which demonstrates that nonadiabatic effects can be obtained accurately by low-order Feynman-Dyson perturbation theory, to lowest order in an expansion parameter of the order of  $(m/M)^{1/2} \ll 1$ . The second simplification is the assumption of a constant density of states (CDOS) over a region  $\pm\bar{\Omega}$  around the Fermi energy  $E_F$ , where  $\bar{\Omega}$  is a few times of the mean phonon frequency. This approximation allows the DOS function  $N(E)$  to be approximated by  $N(E_F)$  in certain energy integrals. The two approximations in fact are related, and it often seems

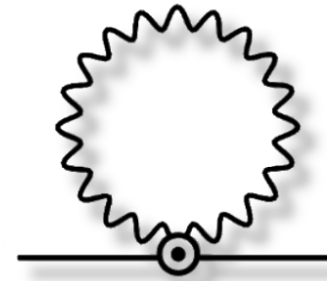
to be assumed that Migdal's theorem is inapplicable if  $N(E)$  is not constant [to within  $(m/M)^{1/2}$ ] over a range  $\pm\bar{\Omega}$  around  $E_F$ . As will be shown in this paper, however, there exists an important regime within which the CDOS approximation may be relaxed in a straightforward manner while retaining Migdal's simplification. The resulting generalizations of the CDOS expressions often are not intuitively obvious, and the consequences involve a reinterpretation of many of the properties of this class of materials.

That structure in the DOS on the scale of  $\bar{\Omega}$  should be expected in crystals containing several transition-metal atoms per unit cell can be deduced from general considerations.<sup>3</sup> Elemental transition metals are known to have peak structure in their DOS which may be only a few tenths of an eV wide. A compound with (for example) ten atoms per unit cell will have 10 times the number of bands in the same overall bandwidth, leading to structure on the order of hundredths of an eV.

26 1186



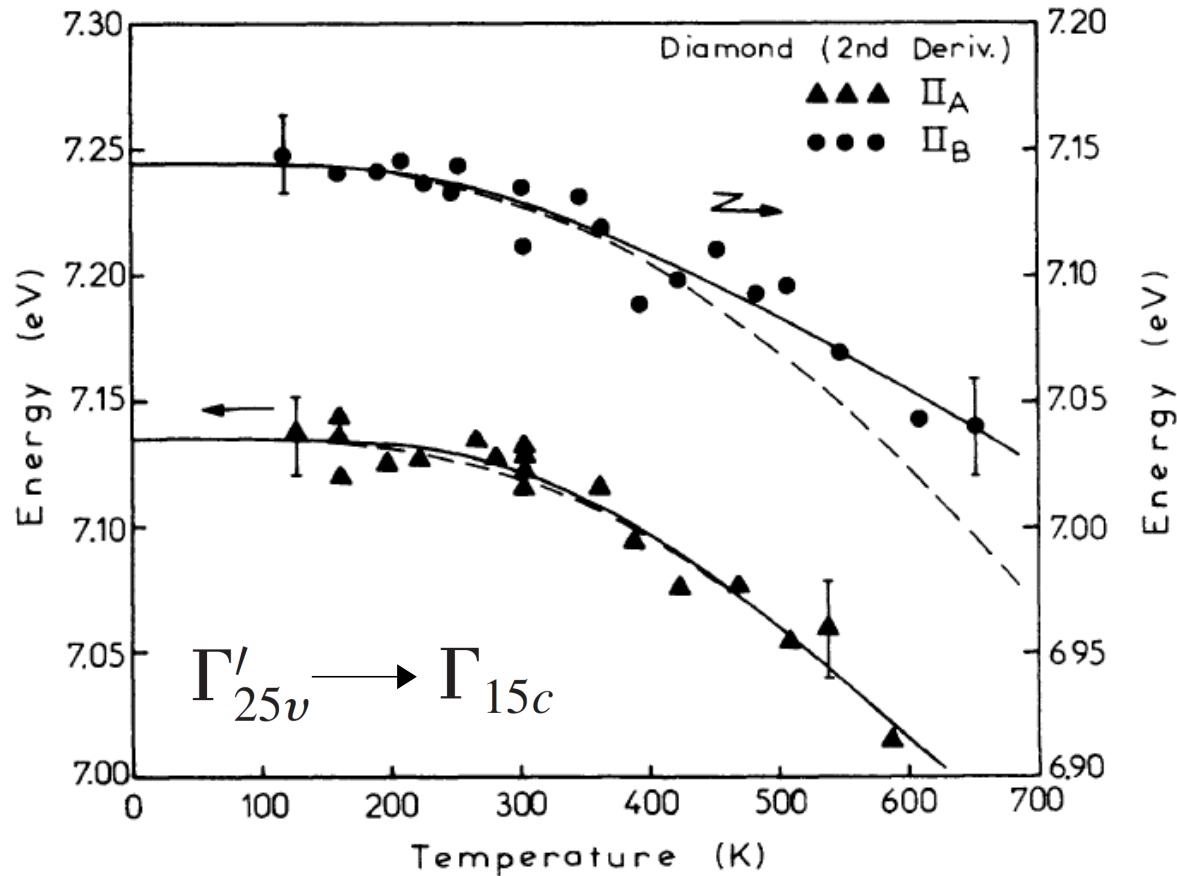
## Where is Debye-Waller in the theory of metals?



In this form of the Hamiltonian  $\Psi$  describes *band electrons*, for which the electron-static lattice and electron-electron interactions have been included in a mean-field sense. For the electron-lattice interaction the remaining coupling is given, to second order in the ion displacement, by the <sup>4</sup> electron-phonon Hamiltonian  $H_{e-ph}$ . The second-order term, which has not been displayed explicitly, is required to keep the theory translationally invariant.<sup>16</sup>

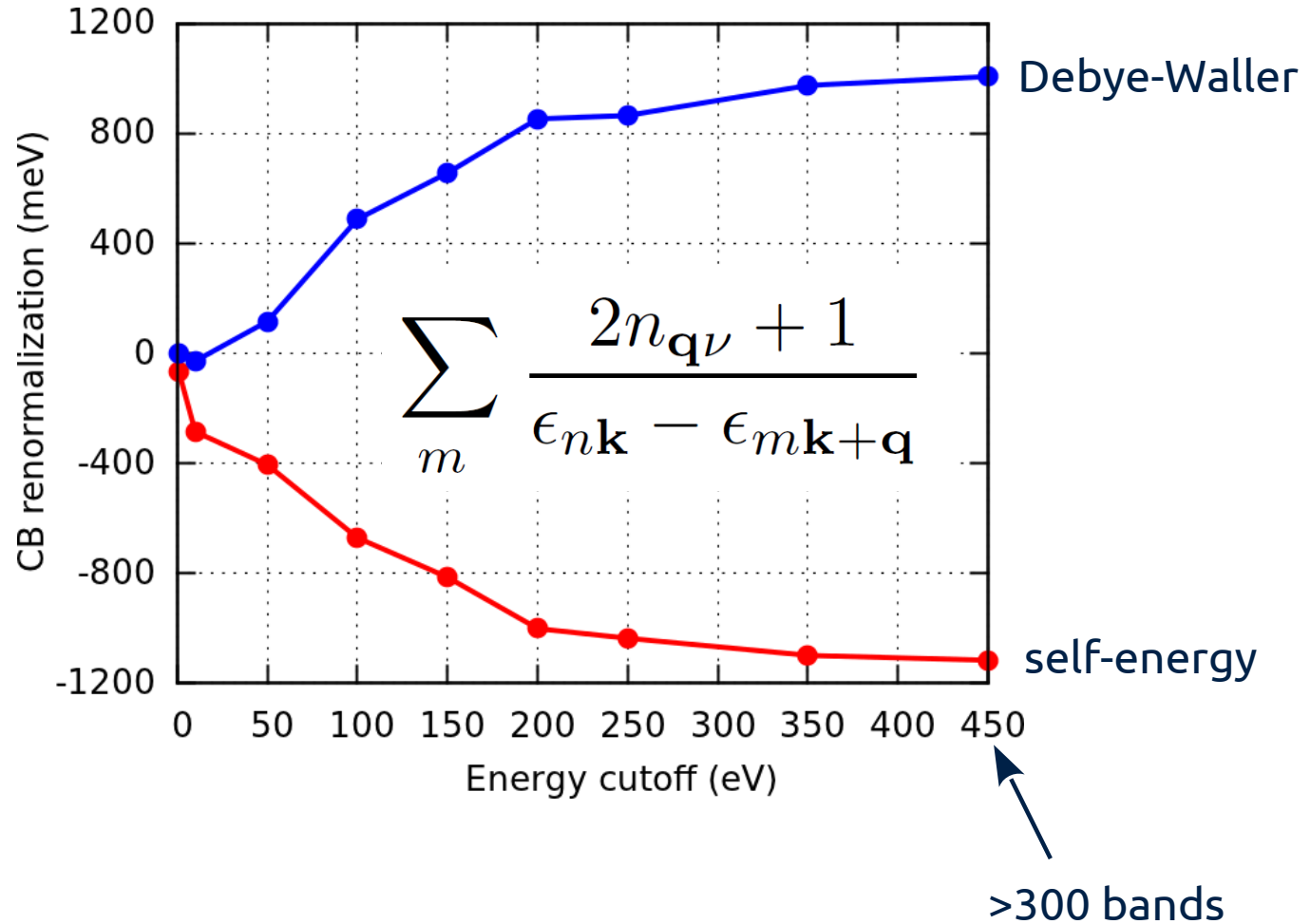
## Diamond

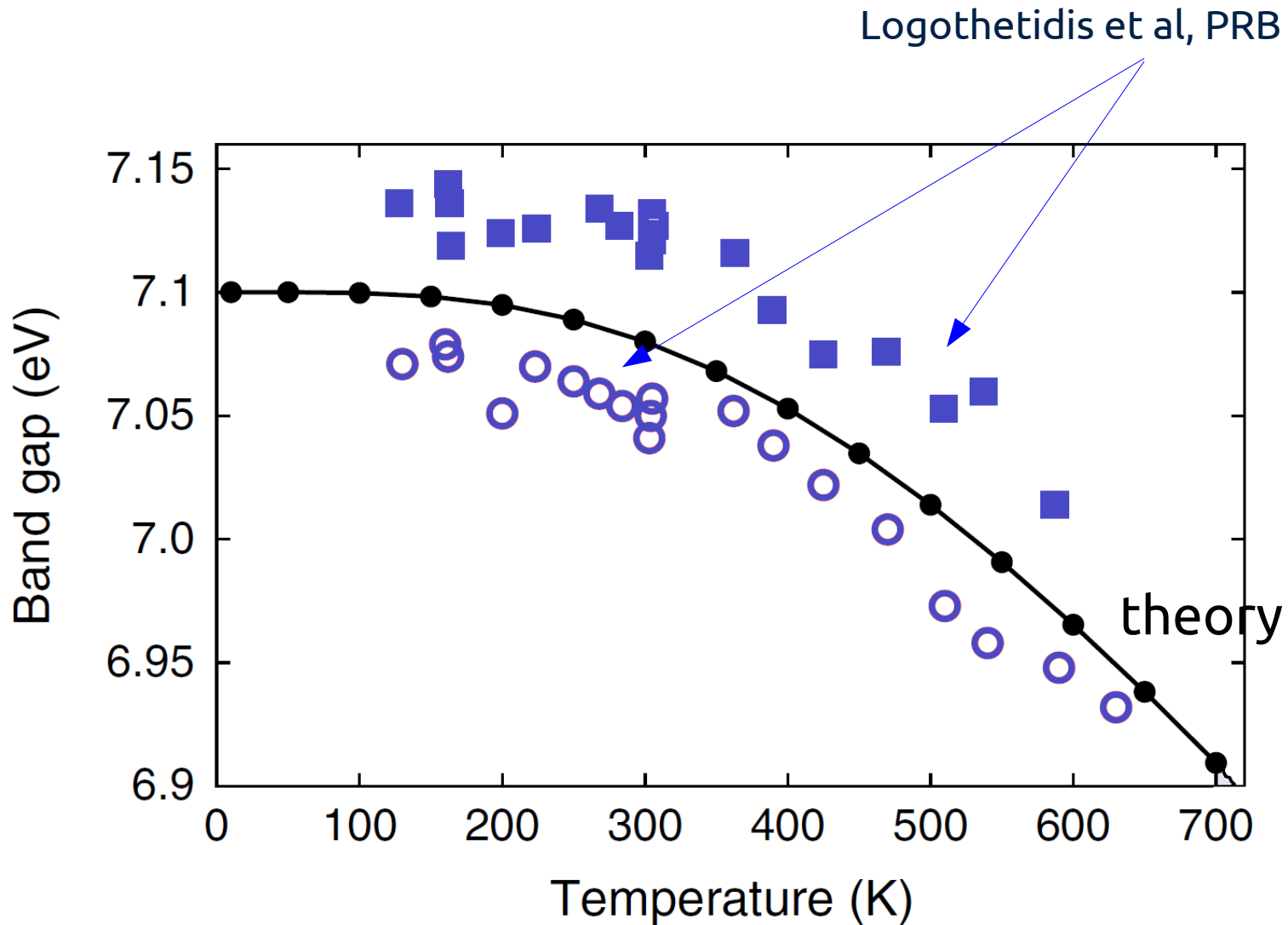
- Negligible thermal expansion
- Negligible excitonic effects



Logothetidis, Petalas, Polatoglou & Fuchs, PRB 1992

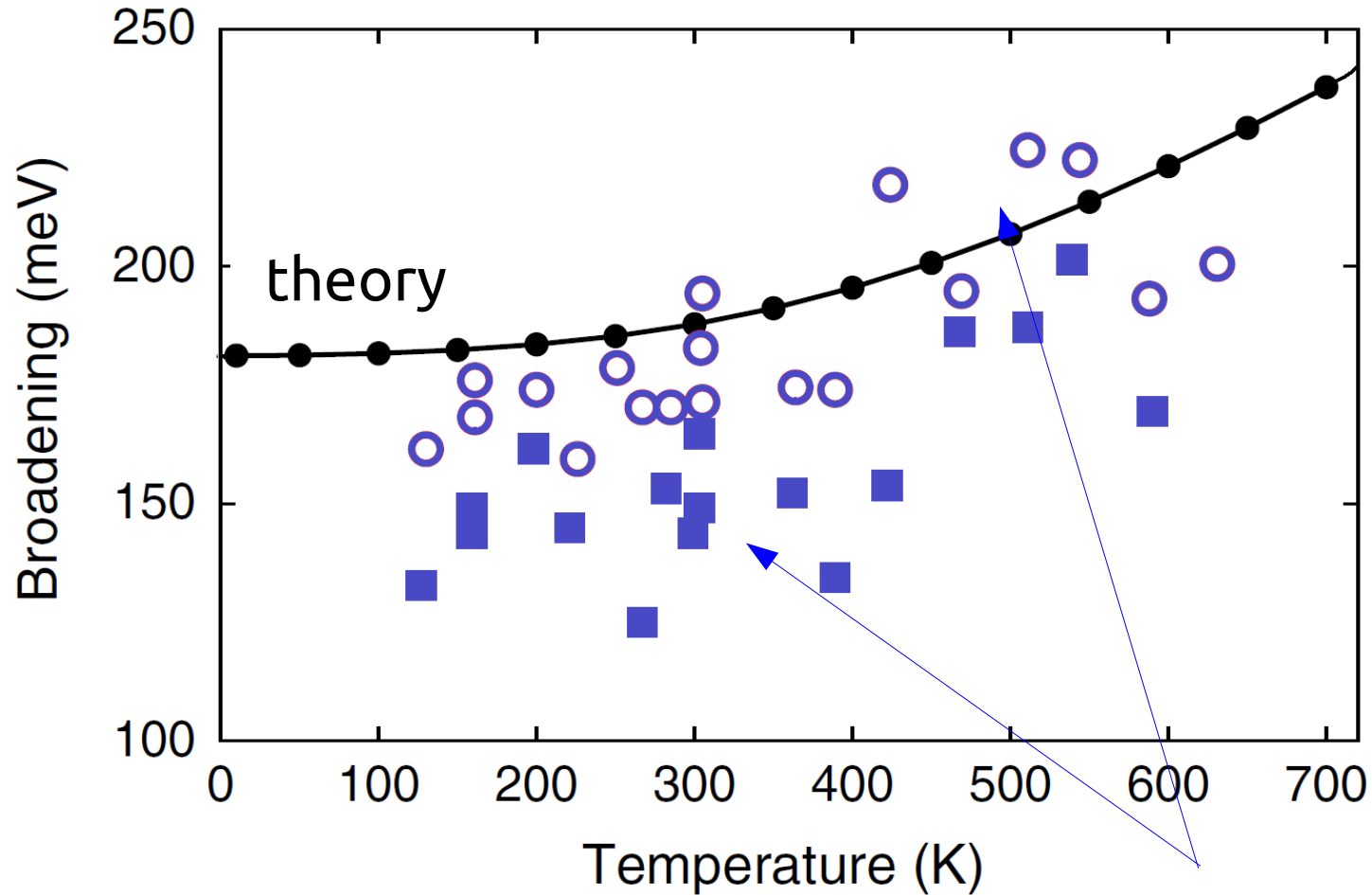
## Slow convergence over unoccupied states





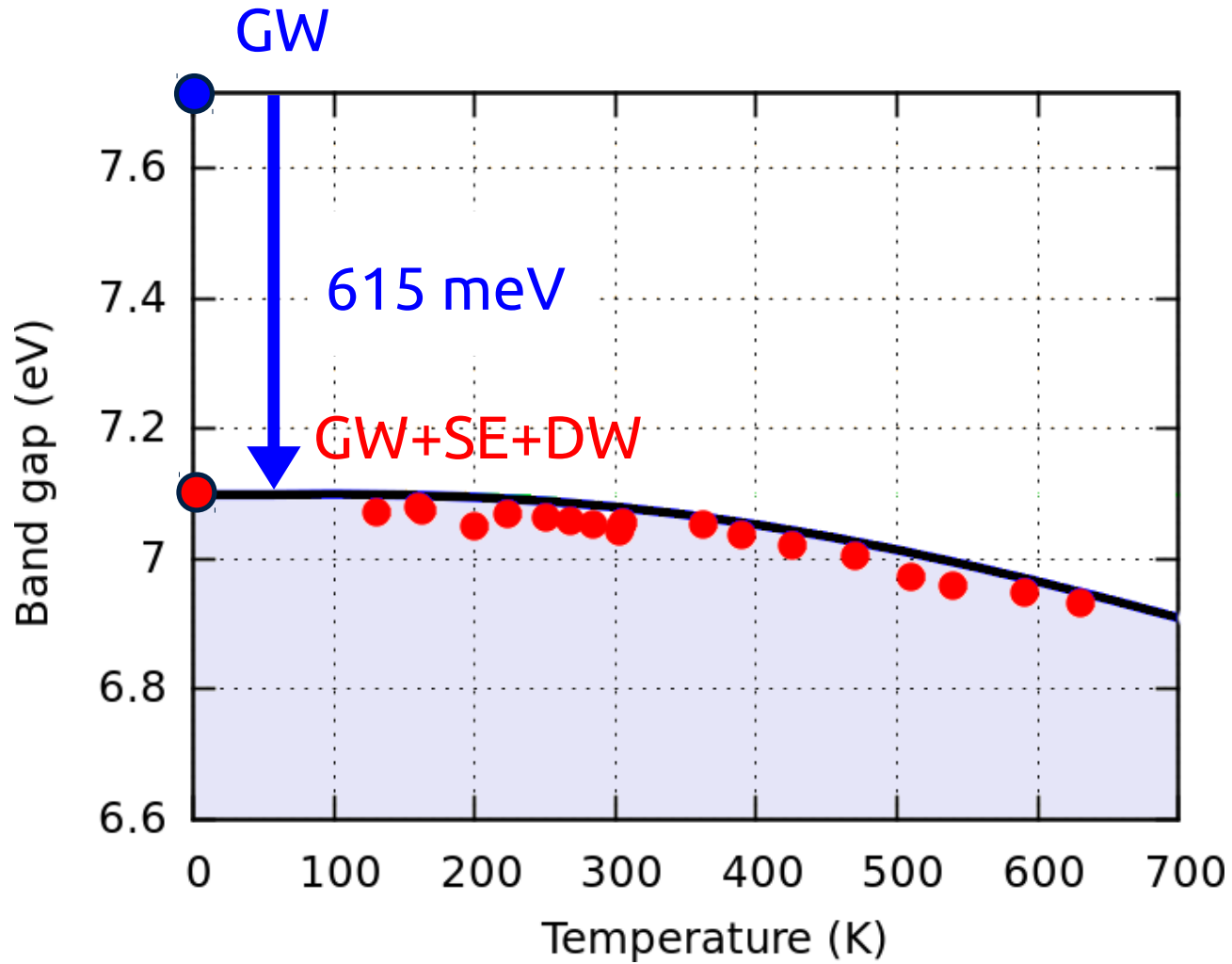
FG, SG Louie & ML Cohen PRL 2010

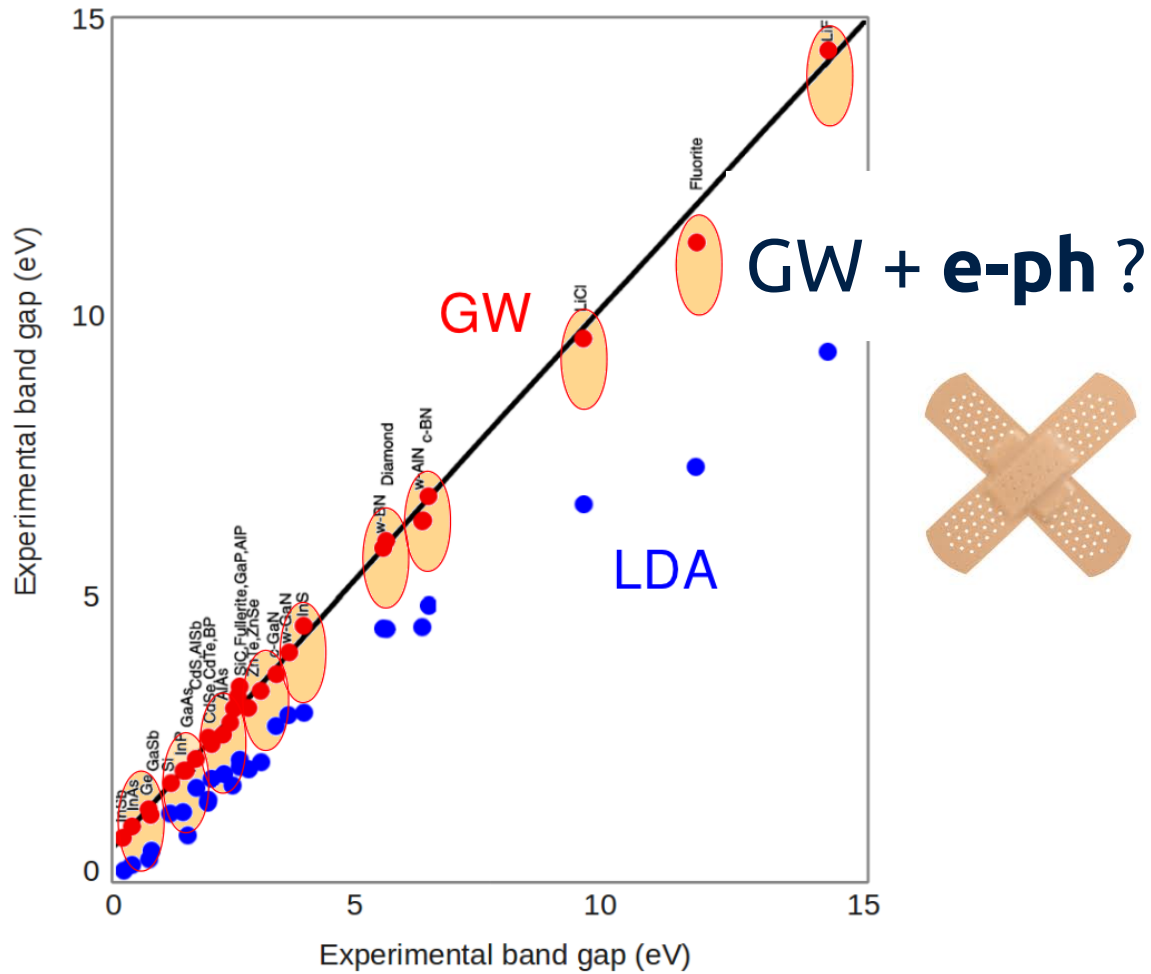




Logothetidis et al, PRB 1992

FG, SG Louie & ML Cohen PRL 2010





data from: SG Louie, Topics in computational materials science 1997

## Open questions



Dynamical theory inconsistent with translational invariance



Linewidth to be used in energy denominators

$$\Sigma_{n\mathbf{k}} \sim \frac{1}{\omega - \epsilon_{m\mathbf{k}+\mathbf{q}} \pm \omega_{\mathbf{q}\nu} - i\delta}$$



Off-diagonal Debye-Waller (Gonze)



Hedin-Lundqvist formulation missing DW term

$$\Sigma_{\text{ph}}(\mathbf{x}, \mathbf{x}'; \omega) = \frac{i}{2\pi} \int_{-\infty}^{+\infty} d\omega' G(\mathbf{x}, \mathbf{x}', \omega + \omega') W_{\text{ph}}(\mathbf{r}, \mathbf{r}', \omega') e^{i\omega'\delta}$$

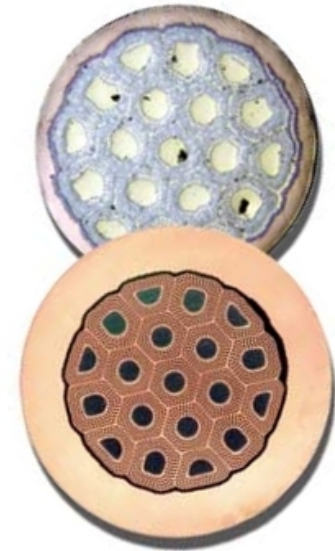
## Metals

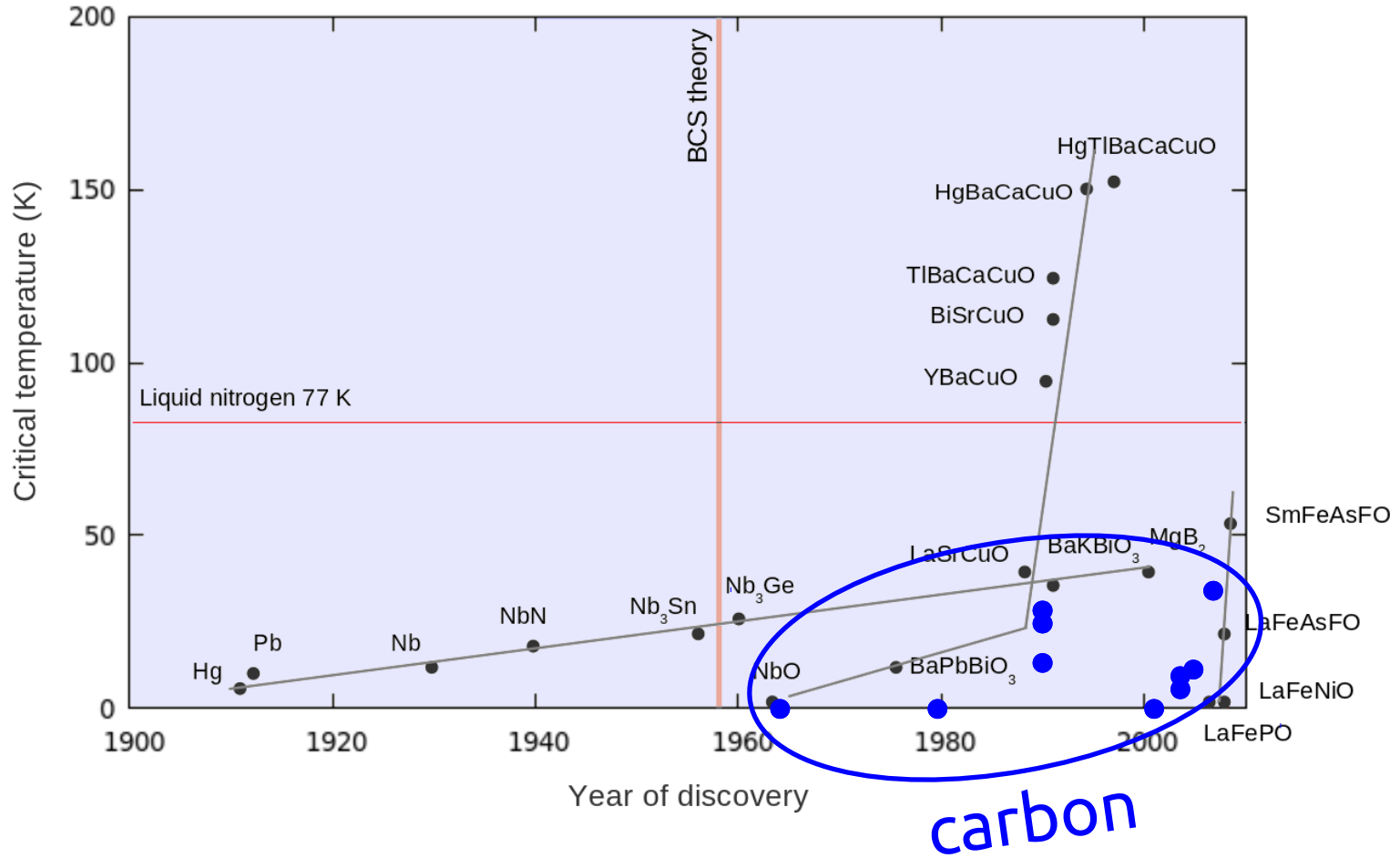


## Insulators



## Superconductors

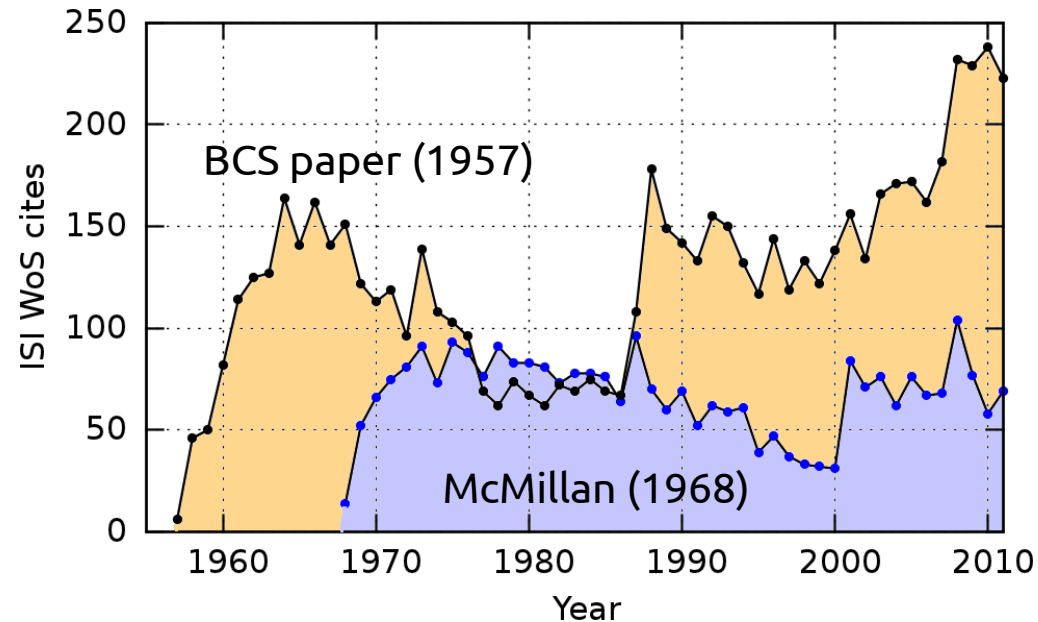
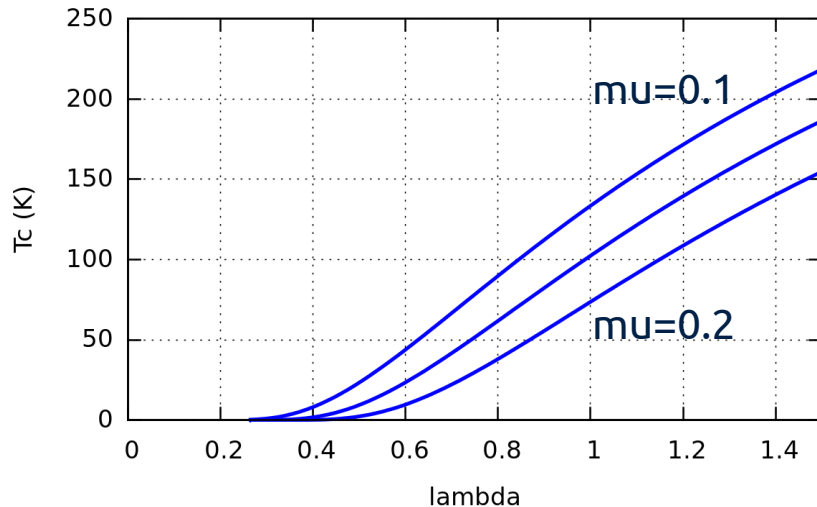




## How can we calculate $T_c$ ? **McMillan equation**



$$T_c = \frac{\omega_{\log}}{1.2} \exp \left[ -\frac{1.04(1 + \lambda)}{\lambda - \mu^*(1 - 0.62\lambda)} \right]$$

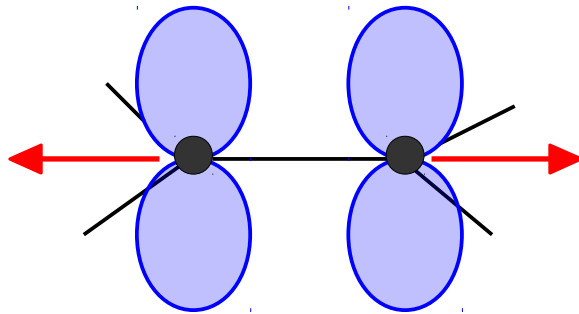


$\lambda$  from **mass-enhancement** in the normal state

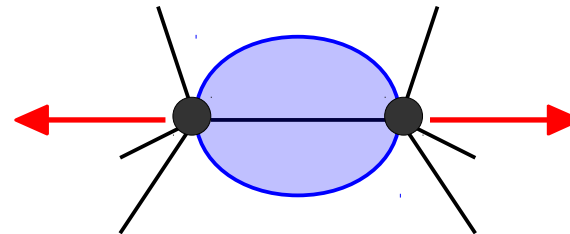
Kindergarten picture:

$$\lambda = N_F V_{ep}$$

sp<sup>2</sup> carbon

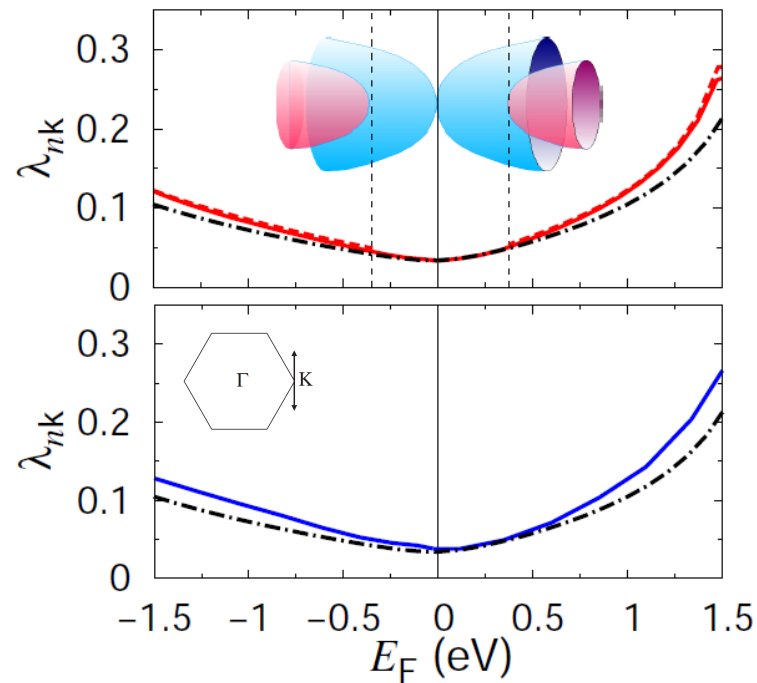
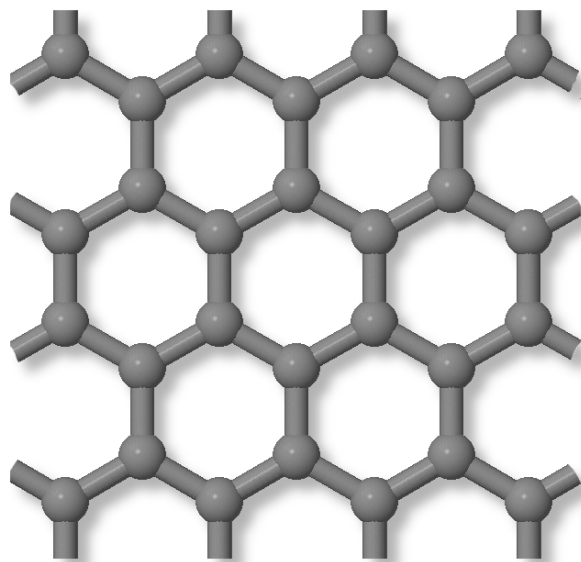


sp<sup>3</sup> carbon



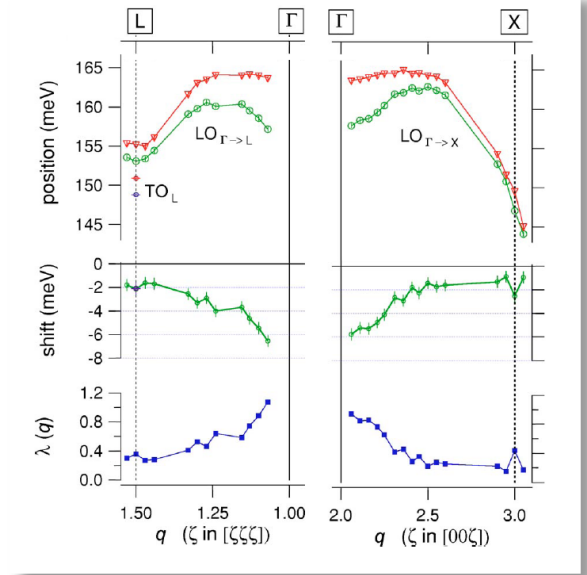
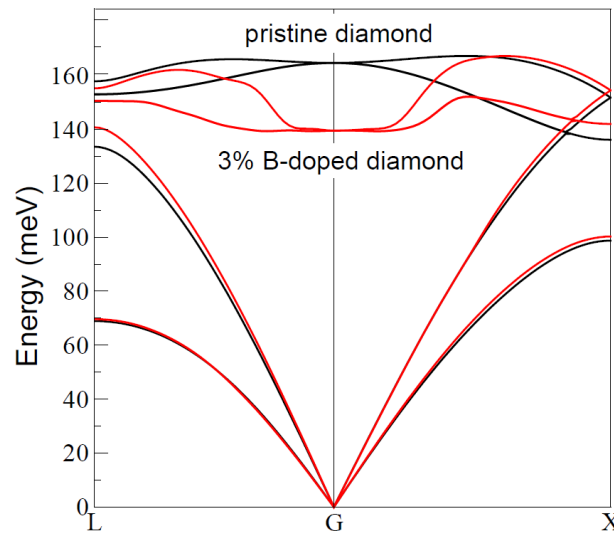


sp<sup>2</sup> carbon: **graphene**



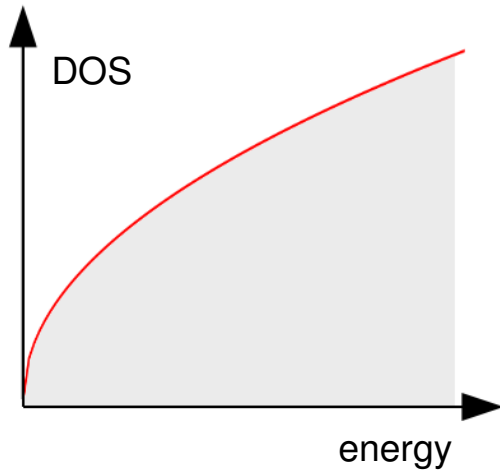
$$\lambda \sim 0.1 - 0.2$$

## sp<sup>3</sup> carbon: diamond



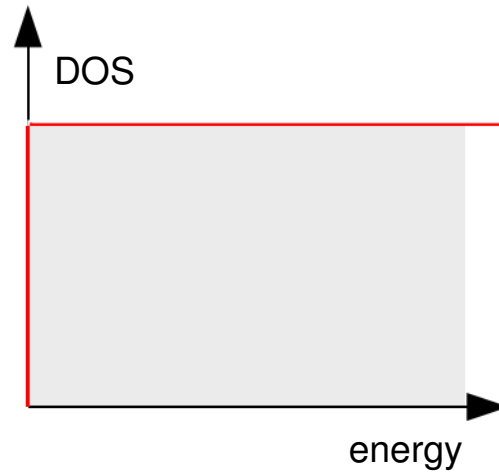
M Hoesch et al, PRB 2007

$$\lambda \sim 0.2 - 0.3$$

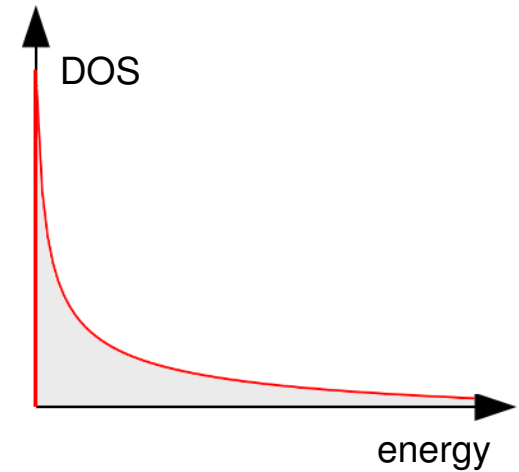


3D

L Boeri, J Kortus  
& OK Andersen PRL 2003



2D



1D

sp<sup>3</sup> carbon & large DOS



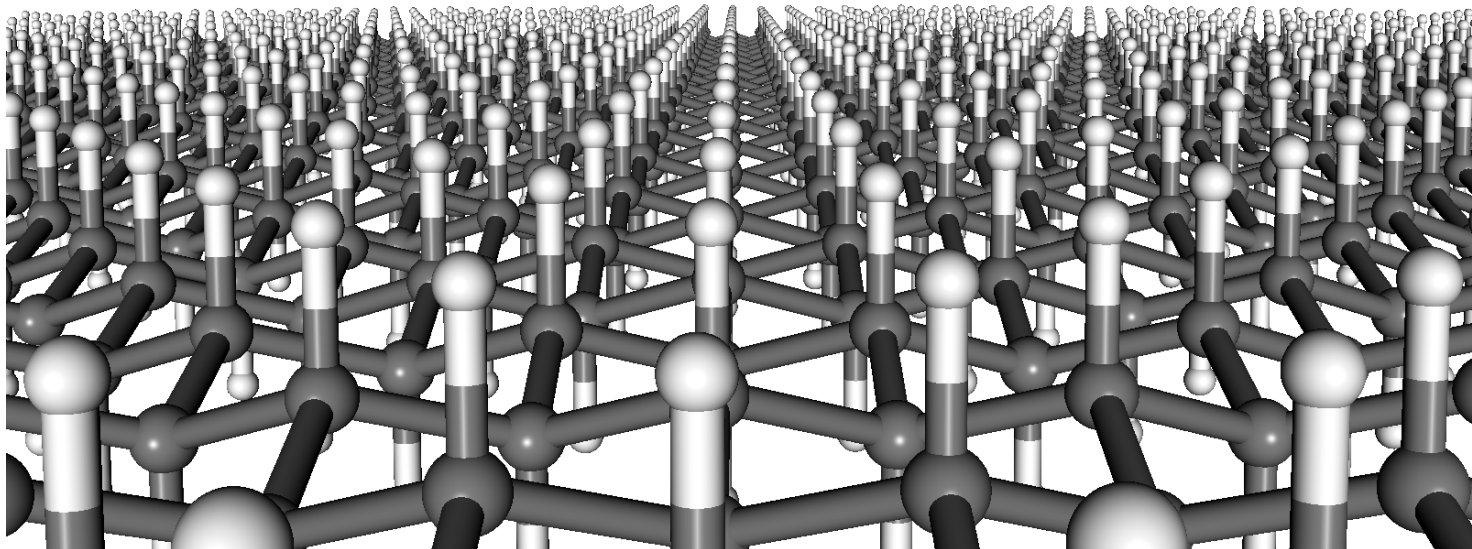
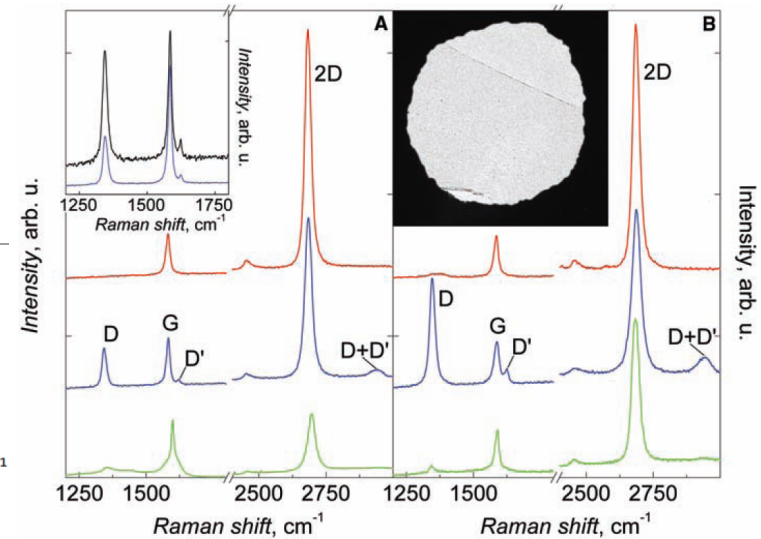
low-dimensional diamond?

## sp<sup>3</sup> carbon: **graphane**

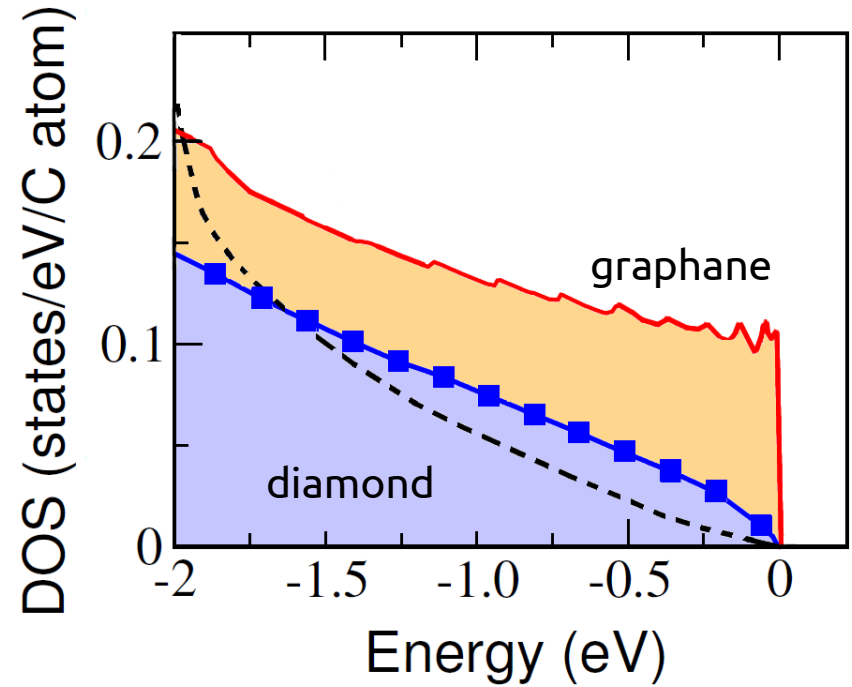
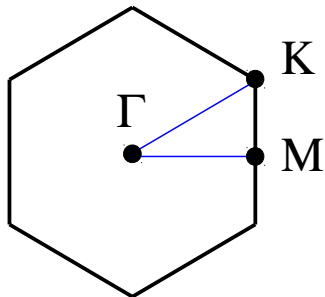
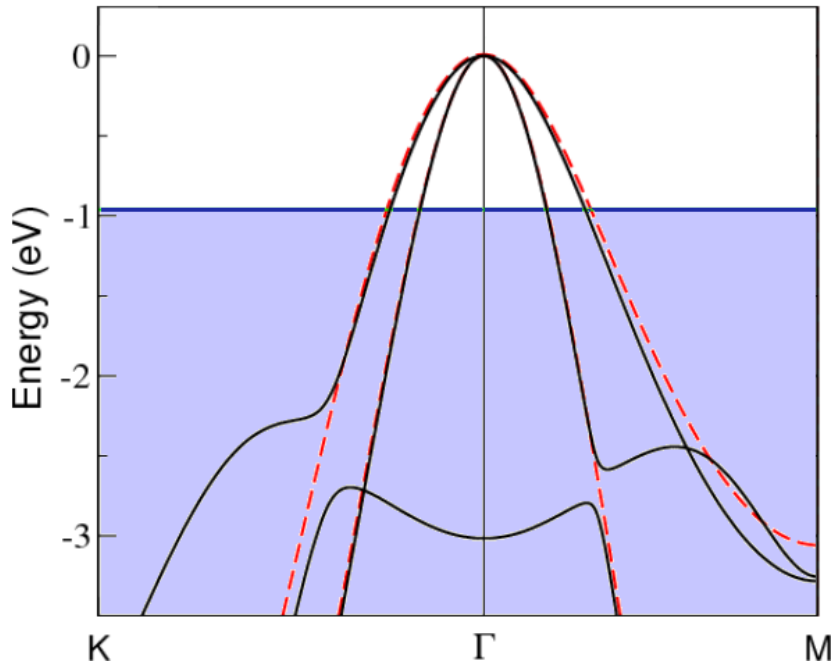
JO Sofo & al, PRB 2007

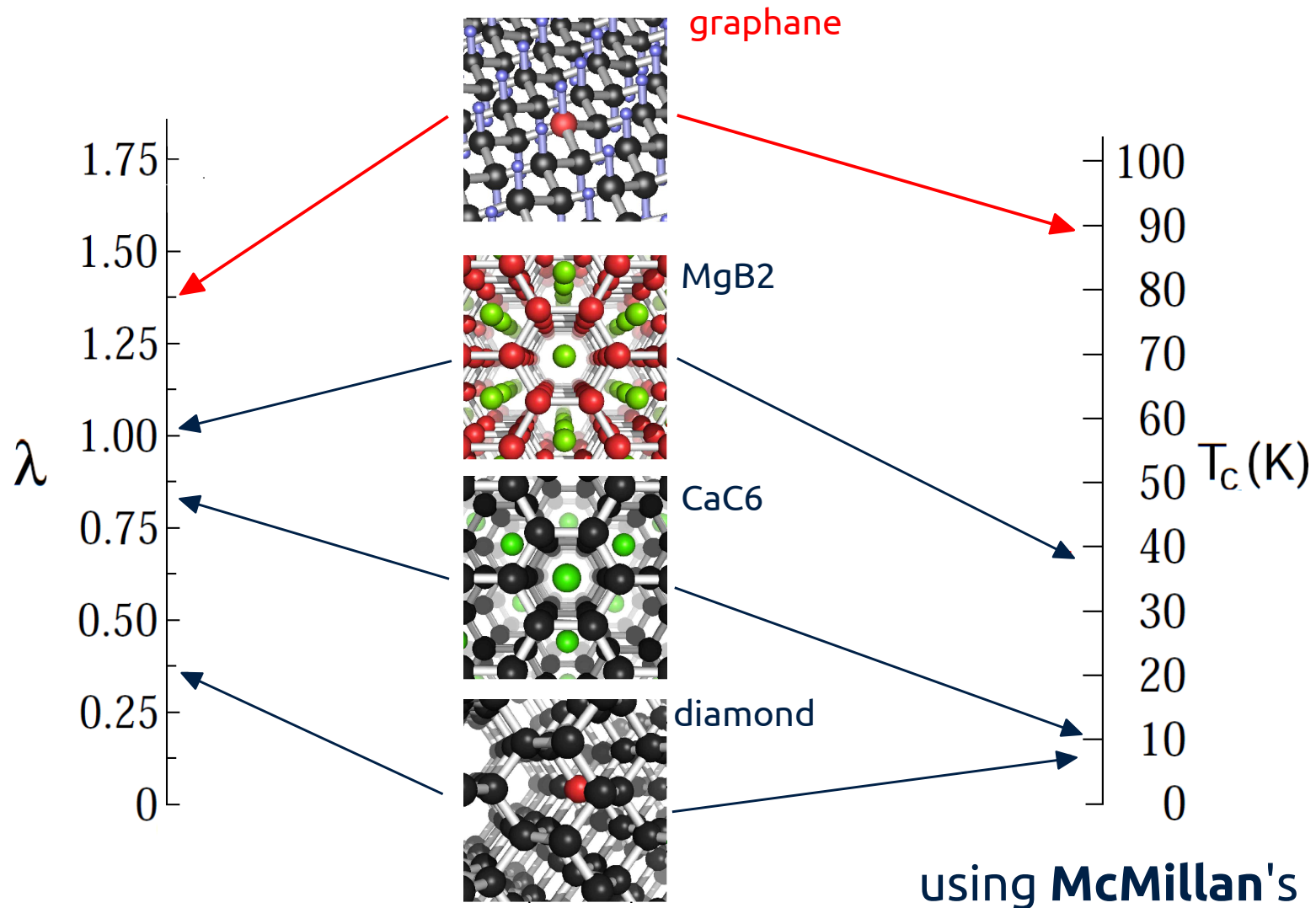
### Control of Graphene's Properties by Reversible Hydrogenation: Evidence for Graphane

D. C. Elias,<sup>1\*</sup> R. R. Nair,<sup>1\*</sup> T. M. G. Mohiuddin,<sup>1</sup> S. V. Morozov,<sup>2</sup> P. Blake,<sup>3</sup> M. P. Halsall,<sup>1</sup>  
A. C. Ferrari,<sup>4</sup> D. W. Boukhvalov,<sup>5</sup> M. I. Katsnelson,<sup>5</sup> A. K. Geim,<sup>1,3</sup> K. S. Novoselov<sup>1†</sup>



p-doped graphane / band structure



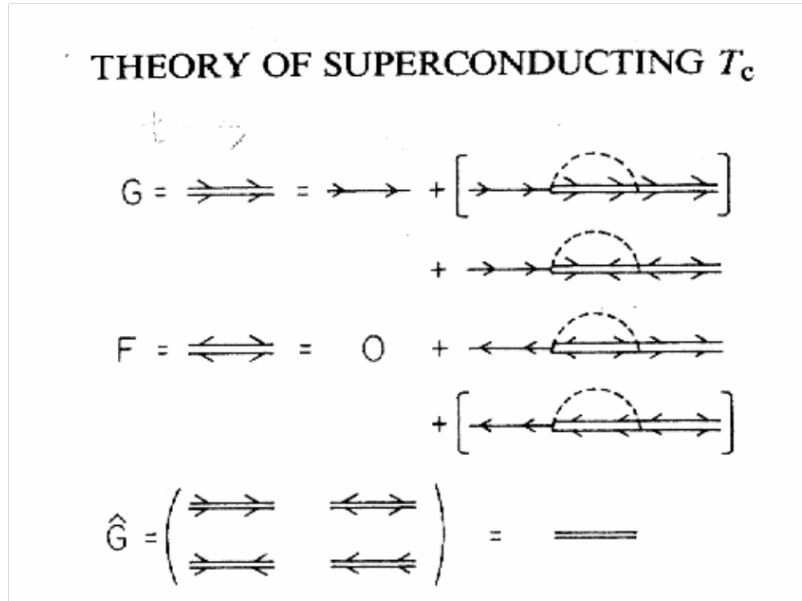


G Savini, AC Ferrari & FG, PRL (2010)

## Beyond McMillan's ? Anisotropic Eliashberg

PB Allen & B Mitrovic, Solid State Physics 1982

- Details of electron-phonon physics



$$\hat{\Sigma}(\mathbf{k}, i\omega_n) = -k_B T \sum_{\mathbf{k}'n'} \hat{\tau}_3 \hat{G}(\mathbf{k}', i\omega_{n'}) \hat{\tau}_3 \sum_{\nu} |g_{\mathbf{k}\mathbf{k}'\nu}|^2 D_{\nu}(\mathbf{k} - \mathbf{k}', i\omega_n - i\omega_{n'})$$

$$- k_B T \sum_{\mathbf{k}'n'} \hat{\tau}_3 \hat{G}(\mathbf{k}', i\omega_{n'}) \hat{\tau}_3 W(\mathbf{k} - \mathbf{k}')$$

See also: ME: HJ Choi et al, Nature 2001' SCDF: M Luders et al, PRB 2005; MAL Marques et al, PRB 2005

## Eliashberg equation for the superconducting gap

$$\Delta(\mathbf{k}, i\omega_n) = \frac{\pi k_B T}{N(\epsilon_F)} \sum_{\mathbf{k}' n'} \delta(\epsilon_{\mathbf{k}'} - \epsilon_F) [\lambda(\mathbf{k}, \mathbf{k}', n - n') - \mu^* \theta(\omega_c - |\omega'_{n'}|)] \frac{\Delta(\mathbf{k}', i\omega_{n'})}{[\omega_{n'}^2 + \Delta^2(\mathbf{k}', i\omega_{n'})]^{1/2}}$$



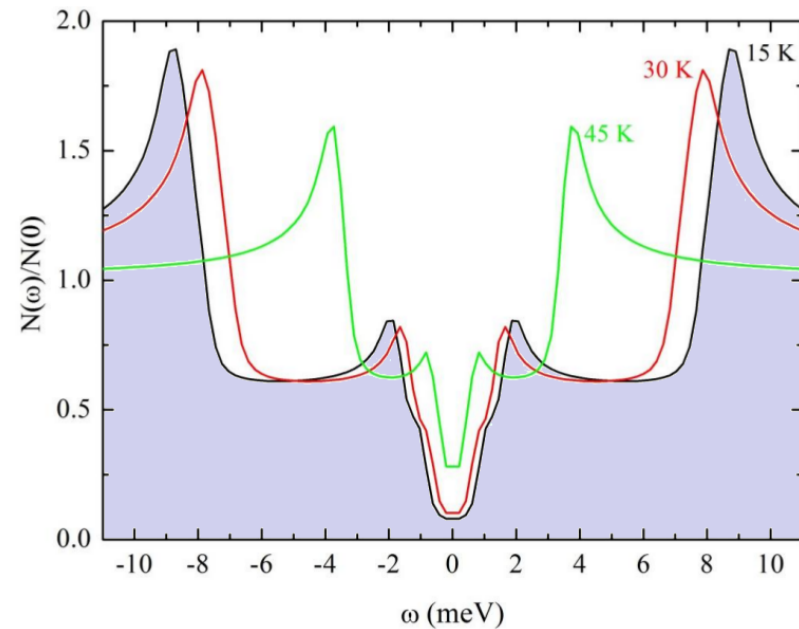
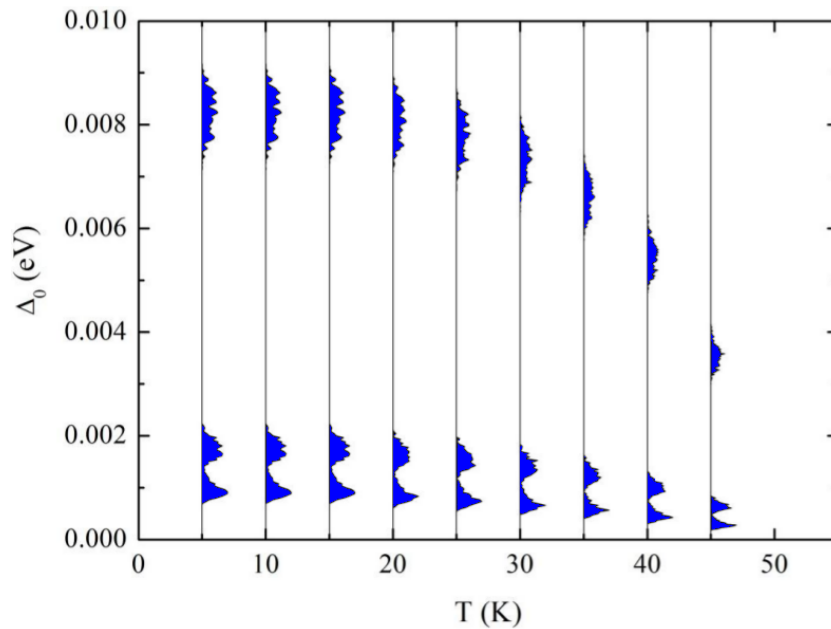
(Renorm factor Z set to 1 in this slide for clarity)





Roxana Margine

## MgB<sub>2</sub>



ER Margine & FG, in preparation

## Open questions



Off-diagonal matrix elements for degenerate bands



Only bands near the Fermi level



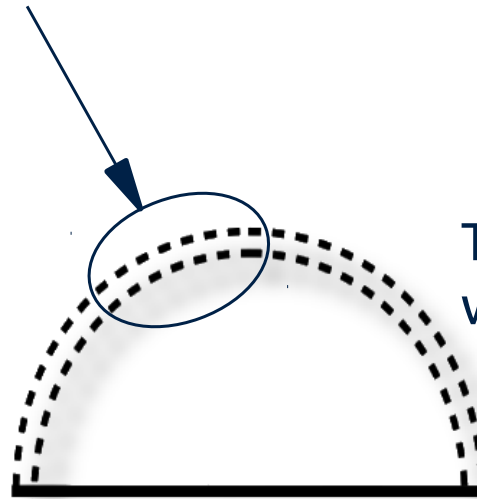
Nearly-constant density-of-states at the Fermi level



what about the Coulomb parameter  $\mu^*$  ?

**Dynamically-screened** Coulomb interaction

$$W(\mathbf{r}, \mathbf{r}'; \omega) = \int d\mathbf{r}'' v(\mathbf{r}, \mathbf{r}'') \epsilon^{-1}(\mathbf{r}'', \mathbf{r}'; \omega)$$



The same quantity that  
we calculate in [SternheimerGW](#)

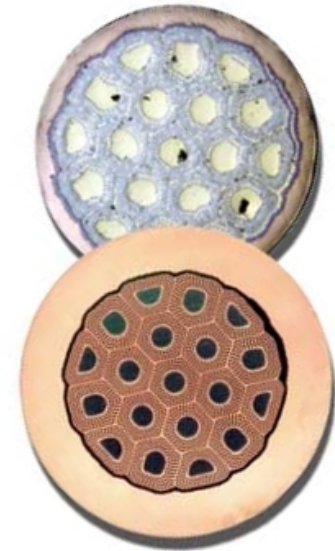
## Metals




## Insulators



## Superconductors







# EPW

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## DOWNLOAD AND INSTALL

Most recent snapshot of the code available here:  
[EPW-2.3.6.tar.gz](http://www.pwscf.org/downloads/PWversion/4.0.3/espresso-4.0.3.tar.gz)  
 (Standardization of examples - 21 Dec 2011)

EPW-2.3.3 has been downloaded **51 times**.  
 EPW-2.3.4 has been downloaded **227 times**.  
 EPW-2.3.4-patched has been downloaded **205 times**.  
 EPW-2.3.5 has been downloaded **48 times**.  
 EPW-2.3.6 has been downloaded **65 times**.

To install EPW:

1) download version 4.0.3 of Quantum-ESPRESSO here:  
<http://www.pwscf.org/downloads/PWversion/4.0.3/espresso-4.0.3.tar.gz>

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EPW-2.3.6 with QE-4.0.3



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